

# RJE0618JSP

–60V, –10A, P Channel Thermal FET Power Switching

R07DS1147EJ0300 Rev.3.00 Feb 01, 2019

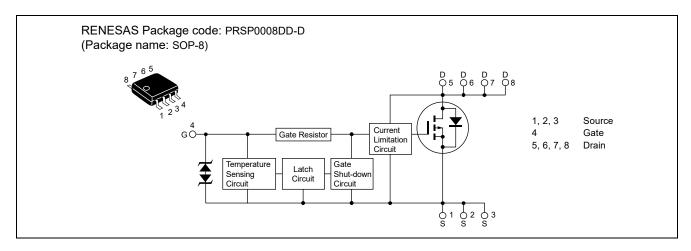
# **Description**

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

#### **Features**

- For Automotive applications
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Latch type shut down operation (need 0 voltage recovery).
- Built-in the current limitation circuit.
- High density mounting
- AEC-Q101 compliant

#### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	-60	V
Gate to source voltage	V <sub>GSS</sub>	-16	V
	V <sub>GSS</sub>	2.5	V
Drain current	I <sub>D</sub> Note3	-10	Α
Body-drain diode reverse drain current	I <sub>DR</sub>	-10	Α
Avalanche current	I <sub>AP</sub> Note 2	-5.4	Α
Avalanche energy	E <sub>AR</sub> Note 2	125	mJ
Channel dissipation	Pch Note 1	2.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1 When using the glass epoxy board (FR4 40  $\times$  40  $\times$  1.6 mm), PW  $\leq$  10 s

- 2. Tch = 25°C, Rg  $\geq$  50  $\Omega$
- 3. It provides by the current limitation lower bound value.

# **Typical Operation Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	VIH	-3.5	_	_	V	
	VIL	_	_	-1.2	V	
Input current	I <sub>IH1</sub>		_	-100	μΑ	$Vi = -8 V, V_{DS} = 0$
(Gate non shut down)	I <sub>IH2</sub>		_	-50	μΑ	$Vi = -3.5 V, V_{DS} = 0$
	I₁∟		_	-10	μΑ	Vi = -1.2 V, V <sub>DS</sub> = 0
Input current	I <sub>IH(sd)1</sub>	_	-0.8	_	mA	$Vi = -8 V, V_{DS} = 0$
(Gate shut down)	I <sub>IH(sd)2</sub>	_	-0.35	_	mA	$Vi = -3.5 V, V_{DS} = 0$
Shut down temperature	Tsd	_	175	_	°C	Channel temperature
Gate operation voltage	Vop	-3.5	_	-12	V	
Drain current	I <sub>D limt</sub>	-10	_	_	Α	$V_{GS} = -12 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 4}}$
(Current limitation value)						

Notes; 4. Pulse test

# **Electrical Characteristics**

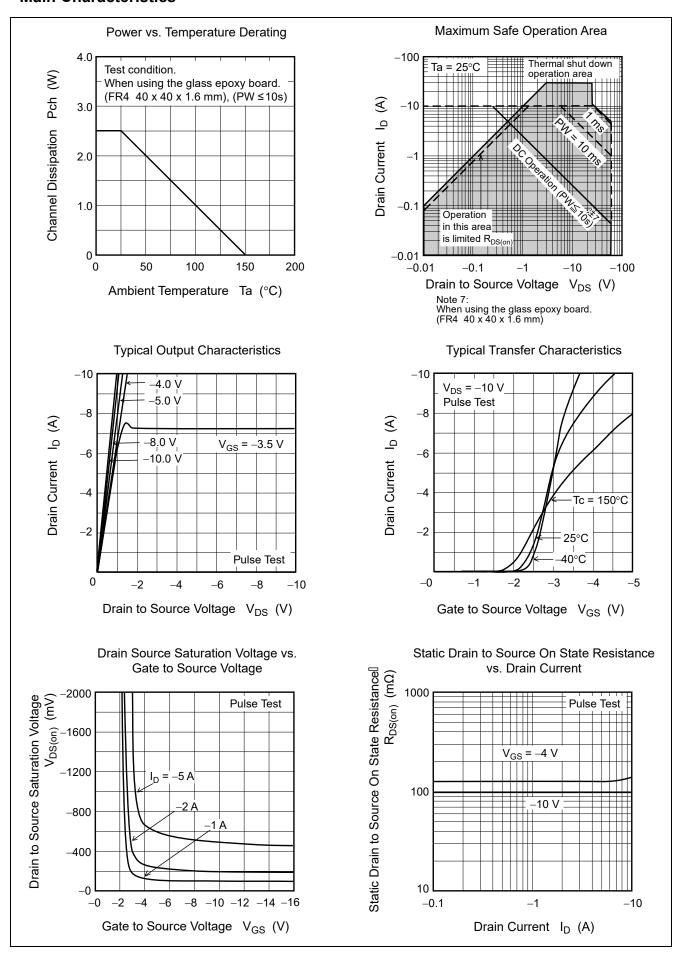
 $(Ta = 25^{\circ}C)$ 

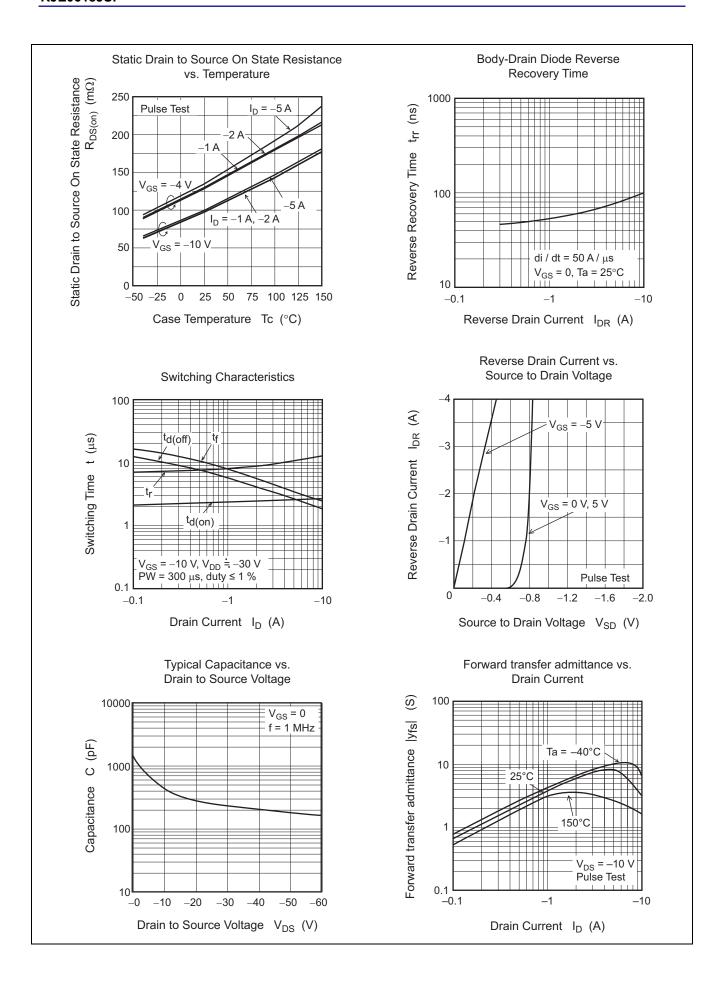
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I <sub>D1</sub>	_	_	-16	Α	$V_{GS} = -3.5 \text{ V}, V_{DS} = -10 \text{ V}$
	I <sub>D2</sub>	_	_	-10	mA	V <sub>GS</sub> = -1.2 V, V <sub>DS</sub> = -10 V
	I <sub>D3</sub>	-10	_	_	Α	$V_{GS} = -12 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 5}}$
Drain to source breakdown	V <sub>(BR)DSS</sub>	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
voltage						
Gate to source breakdown	V <sub>(BR)GSS</sub>	-16	_	_	V	$I_G = -800 \mu A, V_{DS} = 0$
voltage	$V_{(BR)GSS}$	2.5	_	_	V	$I_G = 100 \mu A, V_{DS} = 0$
Gate to source leak current	I <sub>GSS1</sub>	_	_	-100	μΑ	$V_{GS} = -8 \text{ V}, V_{DS} = 0$
	I <sub>GSS2</sub>	_	_	-50	μΑ	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
	I <sub>GSS3</sub>	_	_	-10	μΑ	$V_{GS} = -1.2 \text{ V}, V_{DS} = 0$
	I <sub>GSS4</sub>	_	_	100	μΑ	$V_{GS} = 2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	I <sub>GS(OP)1</sub>	_	-0.8	_	mA	$V_{GS} = -8 \text{ V}, V_{DS} = 0$
	I <sub>GS(OP)2</sub>	_	-0.35	_	mA	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS1</sub>	_	_	-10	μΑ	$V_{DS} = -60 \text{ V}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS2</sub>	_	_	-10	μА	$V_{DS} = -48 \text{ V}, V_{GS} = 0,$
						Ta = 125°C
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	_	-2.1	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$
Forward transfer admittance	y <sub>fs</sub>	5	8.4	_	S	$I_D = -5 \text{ mA}, V_{DS} = -10 \text{ V}^{\text{Note 5}}$
Static drain to source on state	R <sub>DS(on)</sub>	_	134	180	mΩ	$I_D = -5 A$ , $V_{GS} = -6 V^{Note 5}$
resistance	R <sub>DS(on)</sub>	_	98	120	mΩ	$I_D = -5 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 5}}$
Output capacitance	Coss	_	444	_	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{MHz}$
Turn-on delay time	t <sub>d(on)</sub>	_	2.6	_	μS	$V_{GS} = -10 \text{ V}, I_D = -5 \text{ A},$
Rise time	t <sub>r</sub>	_	10.9	_	μs	$R_L = 6 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	2.2	_	μS	
Fall time	t <sub>f</sub>	_	3.4	_	μS	
Body-drain diode forward	$V_{DF}$	_	-0.92	_	V	I <sub>F</sub> = -10 A, V <sub>GS</sub> = 0 Note 5
voltage						
Body-drain diode reverse	t <sub>rr</sub>	_	100		ns	$I_F = -10 \text{ A}, V_{GS} = 0$
recovery time						di <sub>F</sub> /dt = 50 A/μs
Over load shut down	t <sub>os1</sub>	_	2.54	_	ms	$V_{GS} = -5 \text{ V}, V_{DD} = -16 \text{ V}$
operation time Note 6	t <sub>os2</sub>	_	1.35	_	ms	V <sub>GS</sub> = -5 V, V <sub>DD</sub> = -24 V

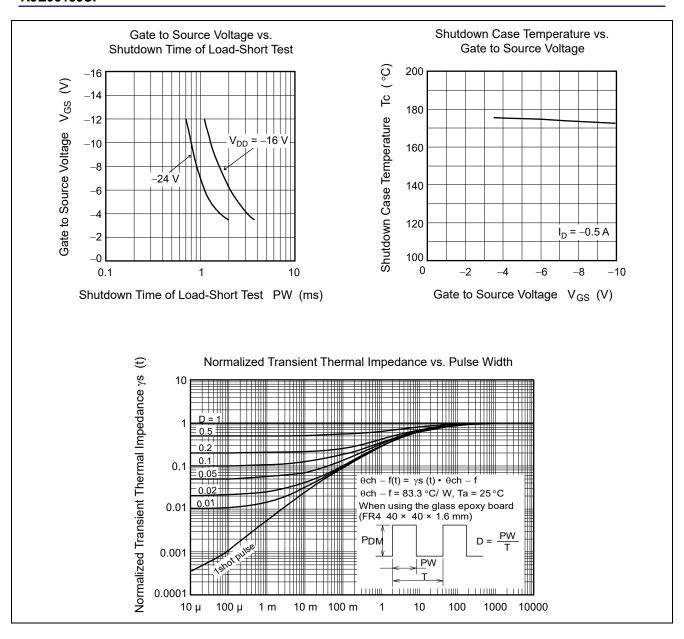
Notes: 5. Pulse test

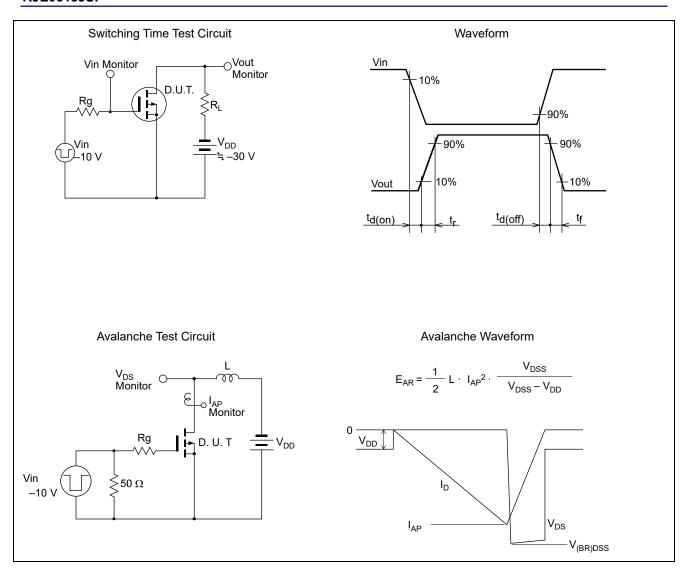
6. Including the junction temperature rise of the over loaded condition.

#### **Main Characteristics**

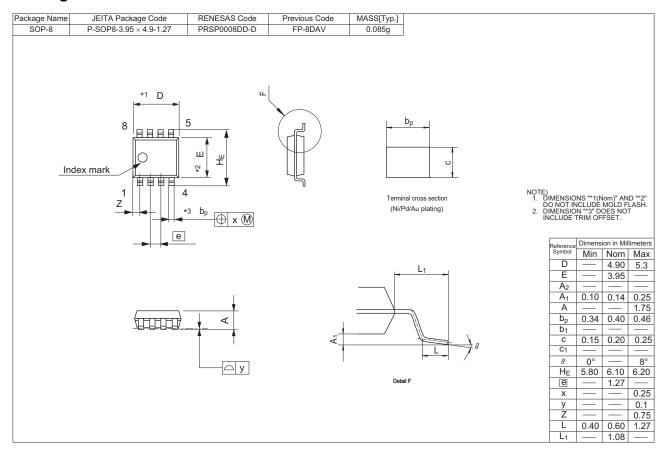








# **Package Dimensions**



# **Ordering Information**

Part No.	Quantity	Shipping Container
RJE0618JSP-00-J0	2500 pcs	Taping

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